## NSN 5961-01-089-8861

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View Online at https://aerobasegroup.com/nsn/5961-01-089-8861 **Inclosure Material:** Metal **Overall Length:** Between 0.250 inches and 0.270 inches Overall Diameter: Between 0.490 inches and 0.510 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 100.0 collector to base voltage, dc and 70.0 collector to emitter voltage/static/base open and 4.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 8.00 amperes source cutoff current **Power Rating Per Characteristic:** 80.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 96214-804087 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unc **Terminal Type And Quantity:** 1 tab, solder lug and 2 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

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No

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